

MiniSKiiP® 3

Twelvepack

SKiiP 35ACC12T7V1

Features*

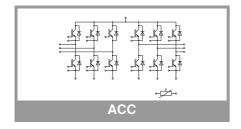
- 1200V Generation 7 IGBTs (T7)
- Robust and soft switching freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognized: File no. E63532

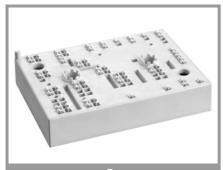
Remarks

- Max. case temperature limited to T_C=T_S=125 °C
- Product reliability results valid for T_j≤150 °C (recommended T_{j,op}=-40...+150 °C)
 MiniSKiiP "Technical Explanations"
- MiniSKiiP "Technical Explanations" and "Mounting Instructions" are part of the data sheet. Please refer to both documents for further information.
- For storage and case temperature with TIM see document: "Technical Explanations Thermal Interface Materials"

Absolute	Maximum Ratings	S		
Symbol	Conditions		Values	Unit
Inverter -	IGBT			
V _{CES}	T _j = 25 °C		1200	V
Ic	λ _{paste} =0.8 W/(mK)	T _s = 70 °C	60	Α
	T _j = 175 °C	T _s = 100 °C	48	Α
I _C	λ _{paste} =2.5 W/(mK)	T _s = 70 °C	68	Α
	T _j = 175 °C	T _s = 100 °C	55	Α
I _{Cnom}			50	Α
I _{CRM}			100	Α
V _{GES}			-20 20	V
t _{psc}	$V_{CC} = 800 \text{ V}$ $V_{GE} \le 15 \text{ V}$ $V_{CES} \le 1200 \text{ V}$	T _j = 175 °C	7	μѕ
Tj			-40 175	°C
Inverse -	Diode			
V_{RRM}	T _j = 25 °C		1200	V
I _F	λ _{paste} =0.8 W/(mK)	T _s = 70 °C	48	Α
	T _j = 175 °C	T _s = 100 °C	39	Α
I _F	$\lambda_{paste}=2.5 \text{ W/(mK)}$	T _s = 70 °C	54	Α
	T _j = 175 °C	T _s = 100 °C	44	Α
I _{FRM}			100	Α
I _{FSM}	$t_p = 10 \text{ ms}, \sin 180^\circ$	°, T _j = 150 °C	270	Α
Tj			-40 175	°C
Module			<u>.</u>	
I _{t(RMS)}	T _{terminal} = 80 °C, 20	A per spring	40	А
T _{stg}	module without TIN	Л	-40 125	°C
V _{isol}	AC sinus 50 Hz, t =	1 min	2500	V

Characte	ristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverter -	IGBT		•			•
V _{CE(sat)}	I _C = 50 A	T _j = 25 °C		1.55	1.70	V
	V _{GE} = 15 V	T _j = 150 °C		1.73	1.88	V
	chiplevel	T _j = 175 °C		1.77	1.92	V
V_{CE0}		T _j = 25 °C		1.00	1.05	V
	chiplevel	T _j = 150 °C		0.80	0.85	V V V
		T _j = 175 °C		0.75	0.80	V
r _{CE}	V 45.V	T _j = 25 °C		11	13	mΩ
	V _{GE} = 15 V chiplevel	T _j = 150 °C		19	21	mΩ
		T _j = 175 °C		20	22	mΩ
$V_{\text{GE(th)}}$	$V_{GE} = V_{CE}, I_{C} = 1.2$	5.15	5.8	6.45	V	
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 1200 \text{ V}, T_j = 25 \text{ °C}$				1	mA
C _{ies}	V 05.V	f = 1 MHz		10.00		nF
C _{oes}	$V_{CE} = 25 \text{ V}$ $V_{GE} = 0 \text{ V}$	f = 1 MHz		0.13		nF
C _{res}	- GE - 0 •	f = 1 MHz		0.04		nF
Q_G	V _{GE} = - 8V + 15		700		nC	
R _{Gint}	T _j = 25 °C			0		Ω





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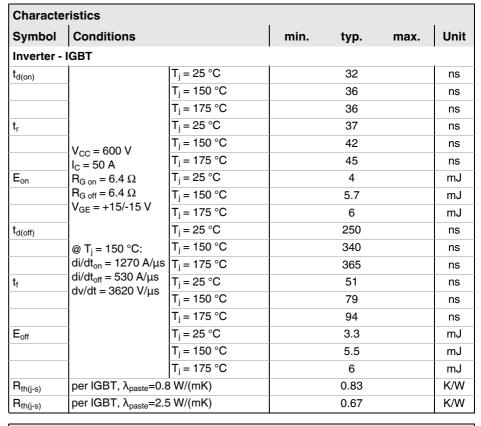
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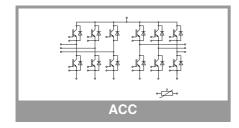
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Characte	eristics					
Symbol	Conditions		min.	typ.	max.	Unit
Inverse -	Diode					
$V_F = V_{EC}$	I _F = 50 A	T _j = 25 °C		2.22	2.54	V
	$V_{GE} = 0 V$	T _j = 150 °C		2.18	2.50	V
	chiplevel	T _j = 175 °C		2.03	2.34	V
V_{F0}		T _j = 25 °C		1.30	1.50	V
	chiplevel	T _j = 150 °C		0.90	1.10	V
		T _j = 175 °C		0.82	0.98	V
r _F		T _j = 25 °C		18	21	mΩ
	chiplevel	T _j = 150 °C		26	28	mΩ mΩ A
		T _j = 175 °C		24	27	mΩ
I _{RRM}		T _j = 25 °C		32		Α
		T _j = 150 °C		42		A A A
	I _F = 50 A	T _j = 175 °C		50		Α
Q _{rr}	$V_{GE} = +15/-15 \text{ V}$	T _j = 25 °C		2.8		μC
	V _{CC} = 600 V	T _j = 150 °C		7.6		μC
	@ T _i = 150 °C:	T _j = 175 °C		8.2		μC
E _{rr}	di/dt _{off} = 1270 A/μs	T _j = 25 °C		0.9		mJ
		T _j = 150 °C		3		mJ
		T _j = 175 °C		4		mJ
R _{th(j-s)}	per Diode, λ _{paste} =0.	8 W/(mK)		0.96		K/W
R _{th(j-s)}	per Diode, λ _{paste} =2.	5 W/(mK)		8.0		K/W
Module	•					
L _{CE}				-		nH
Ms	to heat sink		2		2.5	Nm
W				82		g





MiniSKiiP® 3	G
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Characte	ristics				
Symbol	Conditions	min.	typ.	max.	Unit
Temperati	ure Sensor				
R ₁₀₀	T _r =100°C (R ₂₅ =1000Ω)		1670 ± 3%		Ω
R _(T)	$R_{(T)}=1000\Omega[1+A(T-25^{\circ}C)+B(T-25^{\circ}C)^{2}]$, $A=7.635^{*}10^{-3^{\circ}}C^{-1}$, $B=1.731^{*}10^{-5^{\circ}}C^{-2}$				

Creepage distance (spring to spring) between temperature sensor and DC- = 0.8mm (CTI 600)

Twelvepack

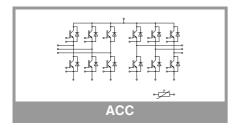
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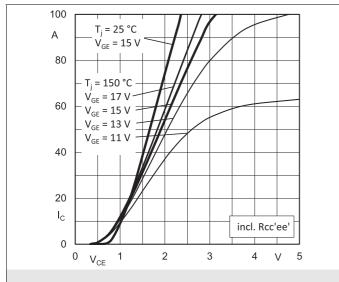


Fig. 1: Typ. output characteristic

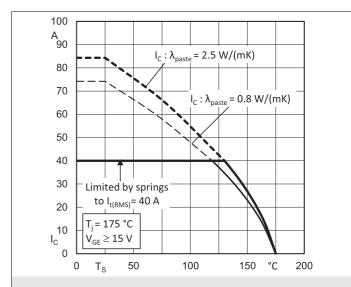


Fig. 2: Rated current vs. temperature Ic = f (Ts)

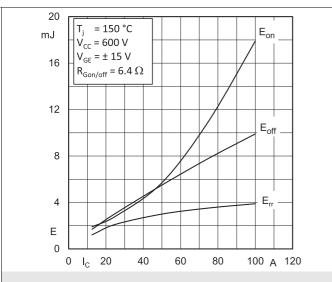


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

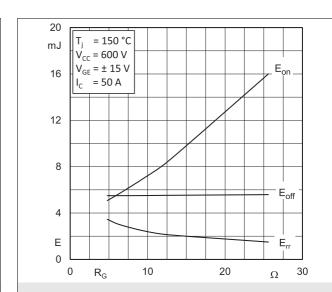


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

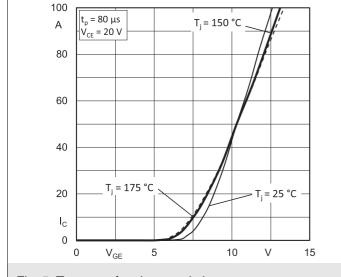


Fig. 5: Typ. transfer characteristic

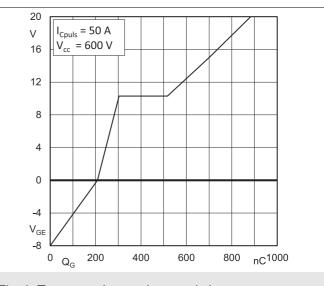


Fig. 6: Typ. gate charge characteristic

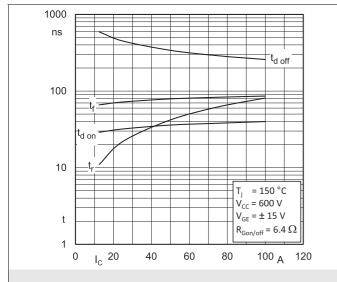


Fig. 7: Typ. switching times vs. I_C

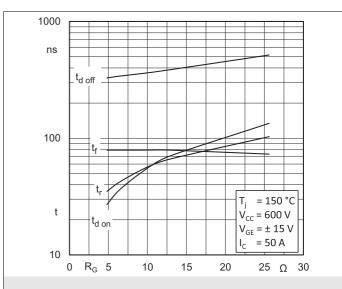


Fig. 8: Typ. switching times vs. gate resistor R_G

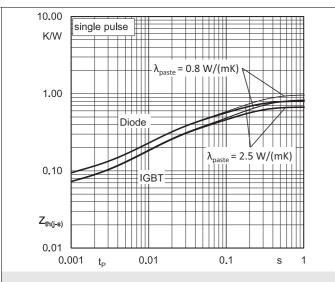


Fig. 9: Typ. transient thermal impedance

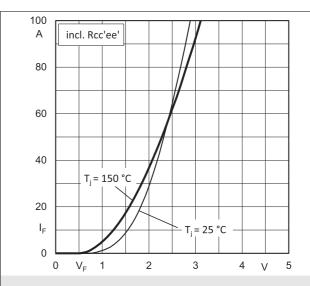


Fig. 10: Typ. CAL diode forward characteristic

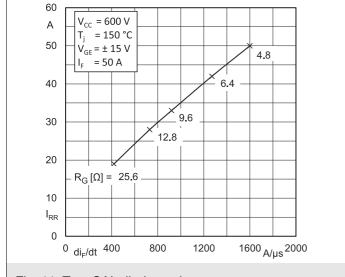


Fig. 11: Typ. CAL diode peak reverse recovery current

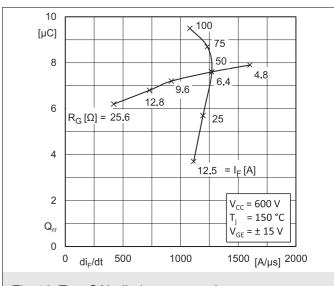


Fig. 12: Typ. CAL diode recovery charge

E1

g1

L1

Pinout

78 💢 🤾 68

69 53 **5**53 **5**2 **5**2 **5**2

					P	in out					
Pin	Χ	Υ	Function	Pin	X	Y	Function	Pin	X	Υ	Function
1	15,83	-25,30	DC+	31	-16,05	-15,02		61	-39,33	25,30	
2	15,83	-6,40	g11	32	-16,05			62	-40,23	-25,30	
3	15,83	-3,20	E11	33	-16,05	-8,62		63	-40,23	-22,10	
4	15,83	, 0	W	34	-16,05	-5,42	U	64	-40,23	-15,70	
5	15,83	3,20	W	35		-25,30	DC+	65	-40,23		
6	15,83	6,40		36	-19,70	-15,02		66	-40,23	-9,30	
7	15,83	15,70	DC-/W	37	-19,70	-11,82	g7	67	-40,23	-6,10	L2
8	15,83	18,90	DC-/W	38	-19,70	-8,62	E7	68	-50,18	- 25,30	L1
9	15,83	22,10	E12	39	-19,70	-5,42	U	69	-50,18	- 22,10	
10	15,83	25,30	g12	40	-22,26	-1,00		70	-50,18	-18,90	
11	8,13	-25,30	DC+	41	- 22,26	2,20		71	-50,18	-15,70	
12	8,13	-22,10		42	- 22,68	22,10	E6	72	-50,18	- 9,50	
13	8,13	22,10	DC-/V	43	-22,68	25,30	g6	73	-50,18	-6,30	
14	8,13	25,30	E10	44	-25,91	-1,00		74	-50,18	6,30	
15	1,83	-15,39		45	-25,91	2,20		75	-50,18	9,50	
16	1,83		g9	46	-29,18	8,74	L3	76	-50,18	22,10	
17	1,83	-8,99	E9	47	-29,18	11,94	g5	77	-50,18	25,30	
18	1,83	-5,79	V	48	-32,83	8,74	L3	78	-53,83		
19	0,43	22,10	DC-/V	49	- 32,83	11,94		79	-53,83		g1
20	0,43		g10	50	-35,68			80	- 53,83		E1
21	-1,08			51	-35,68			81	-53,83		
22	-1,83			52	-36,58		DC+	82	-53,83	- 9,50	
23	-1,83			53	-36,58		DC+	83	-53,83	-6,30	
24	-1,83	-8,99		54	-36,58			84	-53,83	3,10	
25	-1,83	- 5,79	V	55	-36,58			85	-53,83	6,30	E2
26	-5,83	3,95		56	-36,58	- 9,30		86	-53,83	9,50	
27	-7,28	22,10	DC-/U	57	-36,58	-6,10	L2	87	-53,83	22,10	E4
28	-7,28	25,30	E8	58	-39,33	15,70	T-	88	-53,83	25,30	g4
29	-14,98	22,10	DC-/U	59	-39,33	18,90	T+				
30 all v	-14,98 ⁄alues i		g8	60	-39,33	22,10					
	4 88		DC-/		g6)	<u>g</u> 43 ∑	8 E8	g1 8	0 E10		10 g12
	. 111 :			50	E6		29 2		19	13	⁹ E12
		٦		DC-/	L3)		P C-/U		DC-/V	Ž Ž	8 DC-/\
		٦	r _ 58		g5	(())			Ţ	⁷ DC-/\
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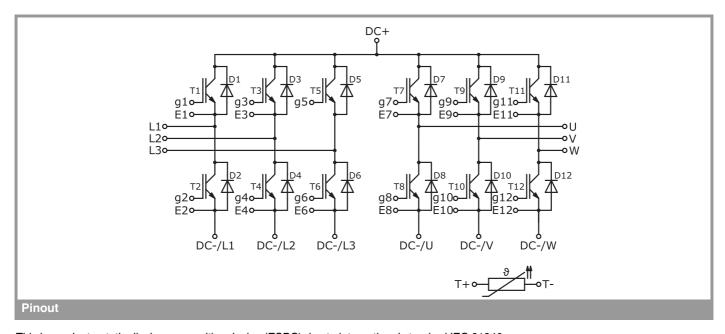
35

11 X1

X

21

DC+



This is an electrostatic discharge sensitive device (ESDS) due to international standard IEC 61340.

*IMPORTANT INFORMATION AND WARNINGS

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